TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

# 2SA1049

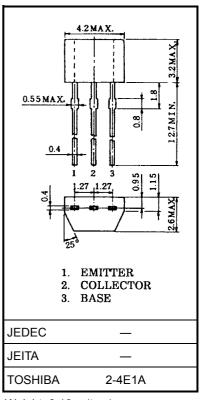
### **Audio Frequency Amplifier Applications**

Unit: mm

- Small package.
- High breakdown voltage:  $V_{CEO} = -120 \text{ V}$
- High hFE: hFE =  $200 \sim 700$
- Excellent hFE linearity: hFE ( $I_C = -0.1 \text{ mA}$ )/hFE ( $I_C = -2 \text{ mA}$ ) = 0.95 (typ.)
- Low noise: NF = 1dB (typ.), 10dB (max)
- Complementary to 2SC2459.

### Maximum Ratings (Ta = 25°C)

| Characteristics             | Symbol           | Rating  | Unit |
|-----------------------------|------------------|---------|------|
| Collector-base voltage      | $V_{CBO}$        | -120    | V    |
| Collector-emitter voltage   | V <sub>CEO</sub> | -120    | V    |
| Emitter-base voltage        | V <sub>EBO</sub> | -5      | V    |
| Collector current           | IC               | -100    | mA   |
| Base current                | ΙB               | -20     | mA   |
| Collector power dissipation | P <sub>C</sub>   | 200     | mW   |
| Junction temperature        | Tj               | 125     | °C   |
| Storage temperature range   | T <sub>stg</sub> | -55~125 | °C   |



Weight: 0.13 g (typ.)

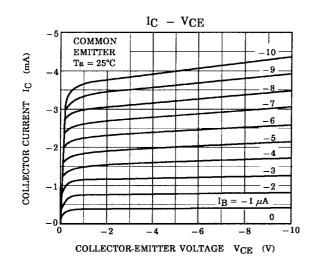
## **Electrical Characteristics (Ta = 25°C)**

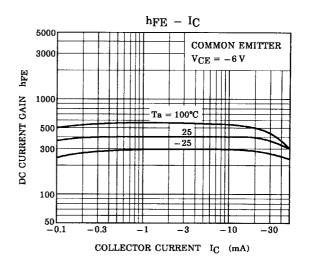
| Characteristics                      | Symbol                    | Test Condition   | Min | Тур. | Max  | Unit |
|--------------------------------------|---------------------------|--|-----|------|------|------|
| Collector cut-off current            | I <sub>CBO</sub>          | $V_{CB} = -120 \text{ V}, I_E = 0$   | _   | _    | -0.1 | μΑ   |
| Emitter cut-off current              | I <sub>EBO</sub>          | $V_{EB} = -5 \text{ V}, I_C = 0$   | _   | _    | -0.1 | μΑ   |
| DC current gain                      | h <sub>FE</sub><br>(Note) | $V_{CE} = -6 \text{ V}, I_{C} = -2 \text{ mA}$                                       | 200 | _    | 700  |      |
| Collector-emitter saturation voltage | V <sub>CE (sat)</sub>     | $I_C = -10 \text{ mA}, I_B = -1 \text{ mA}$  | _   | _    | -0.3 | ٧    |
| Transition frequency                 | f <sub>T</sub>            | $V_{CE} = -6 \text{ V}, I_{C} = -1 \text{ mA}$                                       | _   | 100  | _    | MHz  |
| Collector output capacitance         | C <sub>ob</sub>           | $V_{CB} = -10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$                               | _   | 4    | _    | pF   |
| Noise figure                         | NF                        | $V_{CE} = -6 \text{ V}, I_C = -0.1 \text{ mA}$ f = 1 kHz, $R_G = 10 \text{ k}\Omega$ | _   | 1.0  | 10   | dB   |

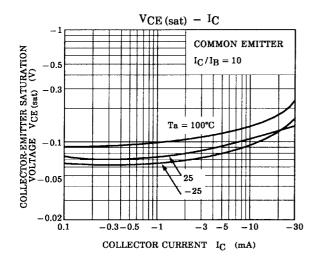
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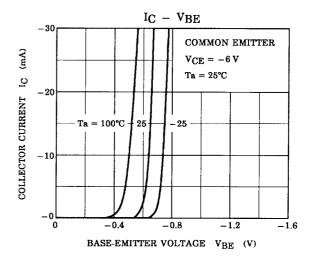
Note: hFE classification GR: 200~400, BL: 350~700

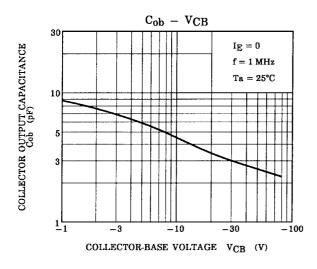
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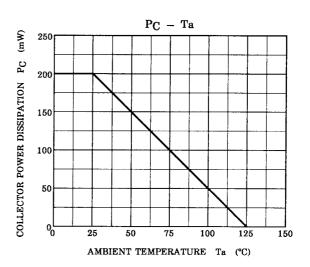












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